

RJH60F4DPQ-A0

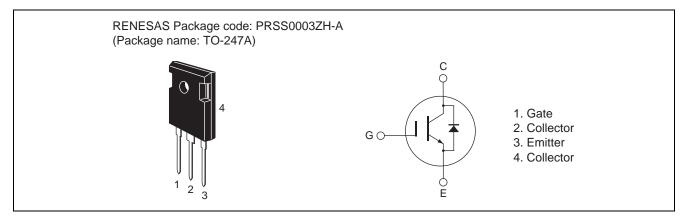
600 V - 30 A - IGBT High Speed Power Switching

R07DS0325EJ0200 Rev.2.00 Jul 22, 2011

Features

- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.4$ V typ. (at $I_C = 30$ A, $V_{GE} = 15$ V, $Ta = 25^{\circ}$ C)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching $t_f = 80$ ns typ. (at $I_C = 30$ A, $V_{CE} = 400$ V, $V_{GE} = 15$ V, $Rg = 5 \Omega$, $Ta = 25^{\circ}C$, inductive load)

Outline



Absolute Maximum Ratings

Item Collector to emitter voltage Gate to emitter voltage		Symbol	Ratings	Unit	
		V _{CES}	600	V V	
		V _{GES}	±30		
Collector current	Tc = 25 °C	I _C Note1	60	A	
	Tc = 100 °C	I _C Note1	30	A	
Collector peak current		ic(peak) ^{Note1}	120	A	
Collector to emitter diode forward peak current		i _{DF} (peak) ^{Note2}	100	A	
Collector dissipation		Pc	235.8	W	
Junction to case therm	al impedance (IGBT)	θ ј-с	0.53	°C/W	
Junction to case thermal impedance (Diode)		θj-cd	2.0	°C/W	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

Notes: 1. Pulse width limited by safe operating area.

2. $PW \leq 5~\mu s,~duty~cycle \leq 1\%$



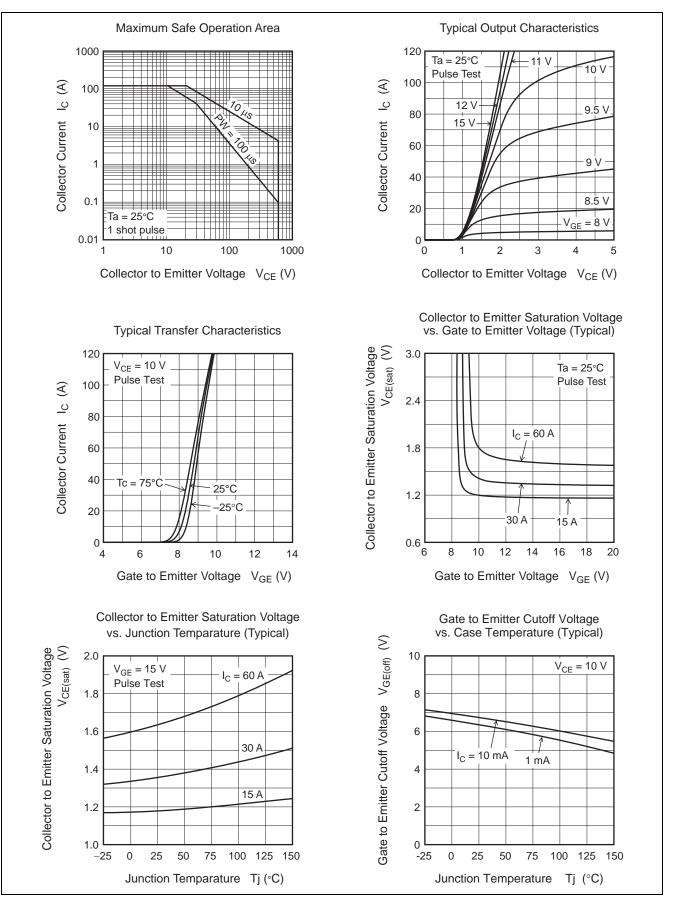
Electrical Characteristics

						$(Tj = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}		_	100	μΑ	$V_{CE} = 600V, V_{GE} = 0$
Gate to emitter leak current	I _{GES}		_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$
Gate to emitter cutoff voltage	V _{GE(off)}	4		8	V	$V_{CE} = 10V, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}		1.4	1.82	V	$I_{C} = 30 \text{ A}, V_{GE} = 15 V^{Note3}$
	V _{CE(sat)}	_	1.7	_	V	$I_{C} = 60 \text{ A}, V_{GE} = 15 V^{Note3}$
Input capacitance	Cies	_	1900	_	pF	V _{CE} = 25 V
Output capacitance	Coes		93		pF	$V_{GE} = 0 V$
Reverse transfer capacitance	Cres	_	33		pF	f = 1 MHz
Switching time	t _{d(on)}	_	45		ns	$\label{eq:lc} \begin{array}{l} I_{C} = 30 \text{ A}, \\ V_{CE} = 400 \text{ V}, V_{GE} = 15 \text{ V} \\ \text{Rg} = 5 \ \Omega^{\text{Note3}} \\ \text{Inductive load} \end{array}$
	tr	_	150	_	ns	
	t _{d(off)}	_	85		ns	
	t _f	_	80		ns	
C-E diode forward voltage	V _{ECF1}		1.2	2.1	V	$I_F = 20 \text{ A}^{\text{Note3}}$
	V _{ECF2}		1.5		V	$I_F = 40 \text{ A}^{\text{Note3}}$
C-E diode reverse recovery time	t _{rr}		90		ns	I _F = 20 A
						di _F /dt = 100 A/µs

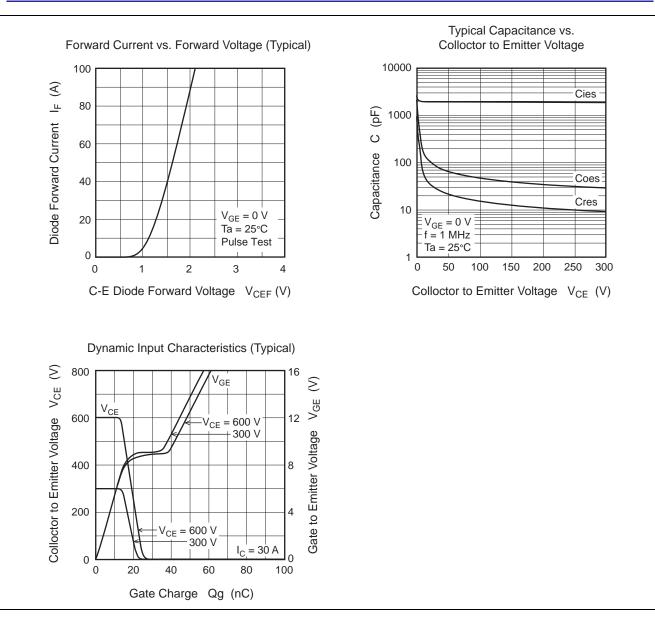
Notes: 3. Pulse test



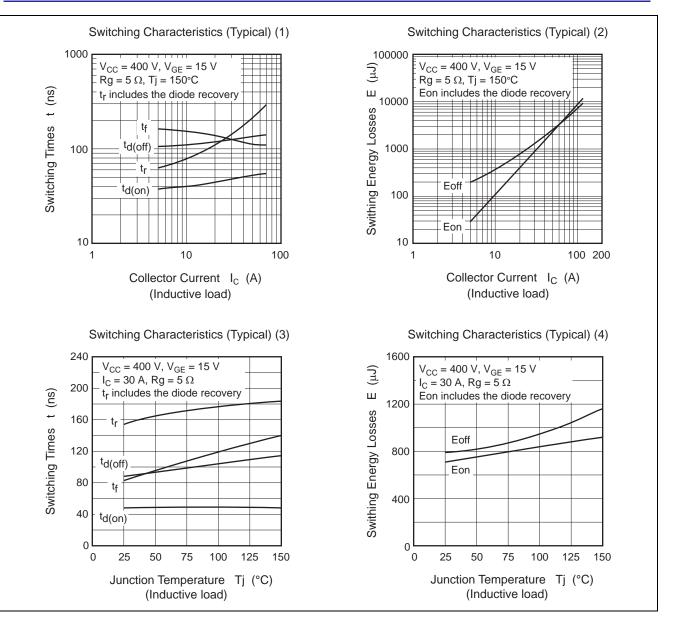
Main Characteristics



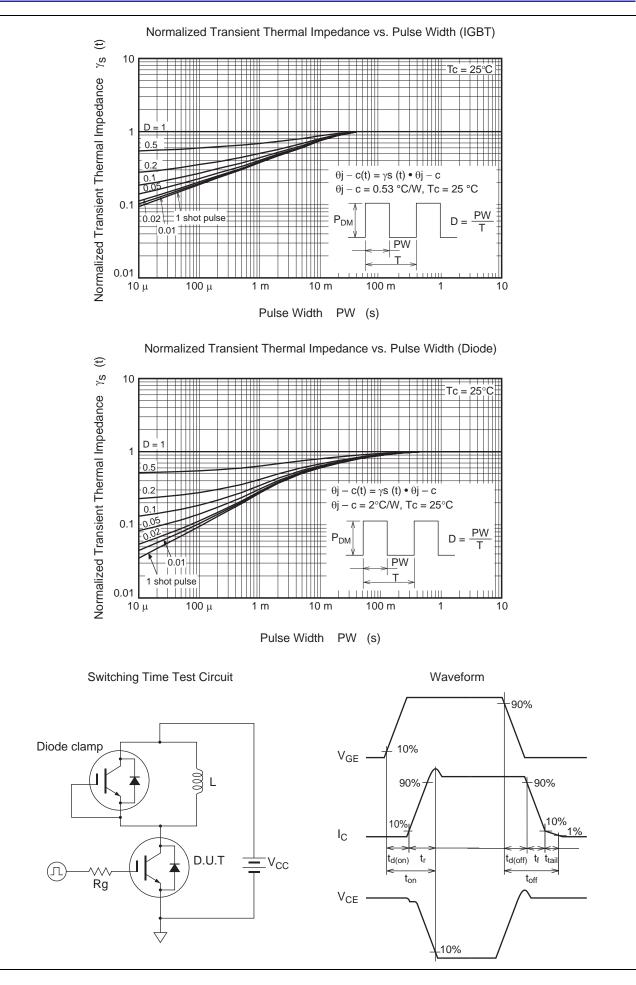




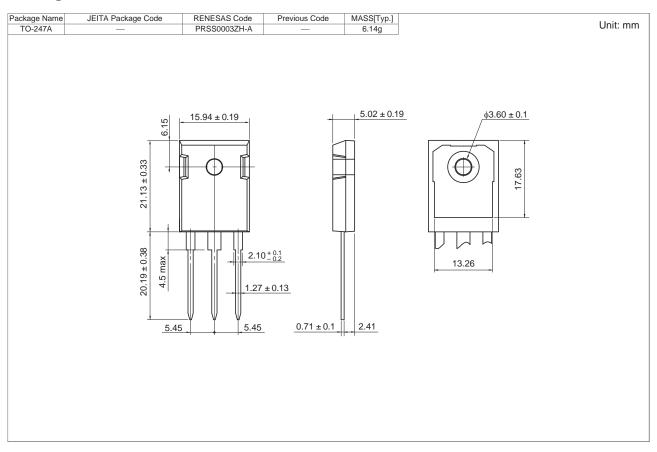








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60F4DPQ-A0-T0	240 pcs	Box (Tube)



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